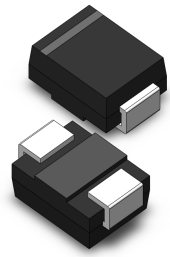
MURS205 - MURS260

SURFACE MOUNT SUPER FAST RECTIFIER DIODES

VOLTAGE RANGE: 50 - 600V
CURRENT: 2.0 A



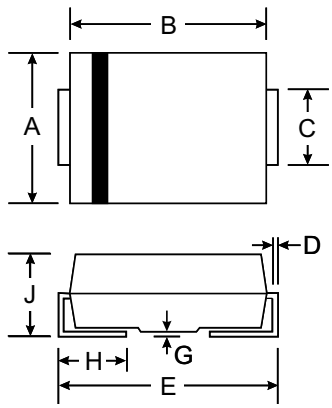
Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Low Power Loss
- Super-Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O

Mechanical Data

- Case: SMB/DO-214AA, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)

RoHS COMPLIANT



SMB(DO-214AA)		
Dim	**Min**	**Max**
A	3.30	3.94
B	4.06	4.70
C	1.91	2.21
D	0.15	0.31
E	5.00	5.59
G	0.10	0.20
H	0.76	1.52
J	2.00	2.62
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics

T_A = 25°C unless otherwise specified

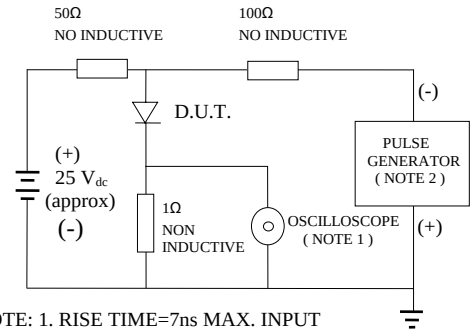
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

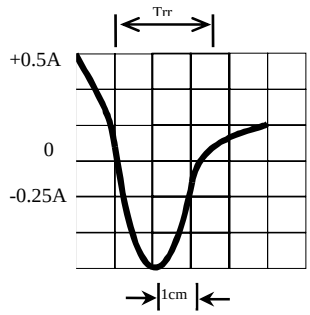
Characteristic	Symbol	MURS 205	MURS 210	MURS 215	MURS 220	MURS 230	MURS 240	MURS 260	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	150	200	300	400	600	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	210	280	420	V
Average Rectified Output Current @T_L = 75 °C	I_O	2.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	40				35			A
Forward Voltage @I_F = 2.0A	V_{FM}	0.95				1.45			V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 125°C	I_{RM}	5.0 250							μA
Reverse Recovery Time (Note 1)	t_{rr}	35							nS
Typical Junction Capacitance (Note 2)	C_j	20				50			pF
Typical Thermal Resistance (Note 3)	$R_{\theta JL}$	40							°C/W
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150							°C

Note: 1. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. See figure 5.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.
3. Mounted on P.C. Board with 8.0mm^2 land area.

RATINGS AND CHARACTERISTIC CURVE MURS205 THRU MURS260

FIG. 1-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC





SET TIME BASE
FOR 10/20 ns/cm

NOTE: 1. RISE TIME=7ns MAX. INPUT IMPEDANCE=1 MOhms 22PF
2. RISE TIME =10ns MAX. SOURCE IMPEDANCE=50 OHMS

FIG. 2-TYPICAL FORWARD CURRENT DERATING CURVE

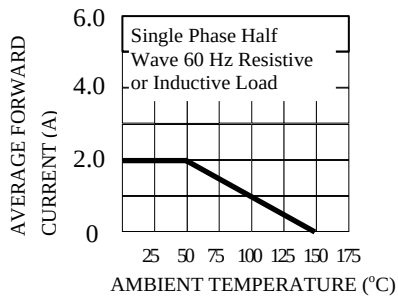


FIG. 3-TYPICAL REVERSE CHARACTERISTICS

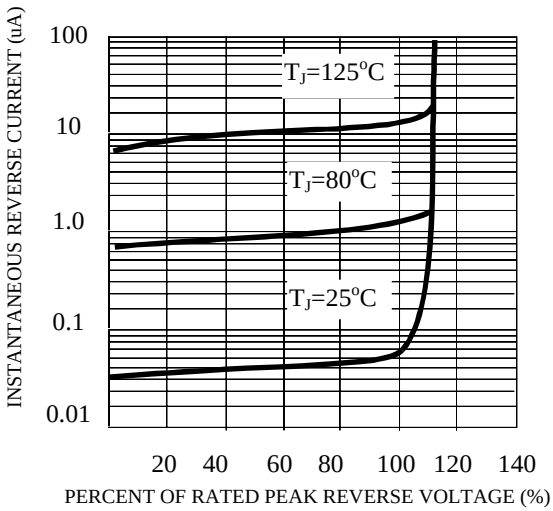


FIG. 4-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

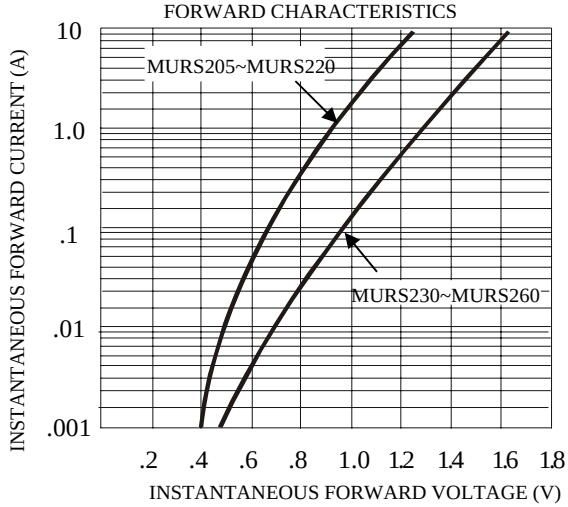


FIG. 5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

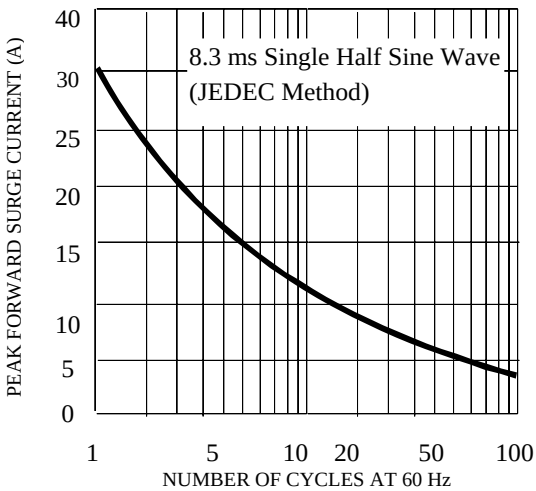


FIG. 6-TYPICAL JUNCTION CAPACITANCE

